Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.357 inches
Terminal Length:
1.625 inches
Overall Diameter:
0.235 inches
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
31.4 breakdown voltage, dc
Current Rating Per Characteristic:
5.00 microamperes forward current, average peak
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector major
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
82349-mil-s-19500/500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

No

Fiig:

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